

■ OUTLINE

The R3112 Series are voltage detector ICs with high detector threshold accuracy and ultra-low supply current by CMOS process, which can be operated at an extremely low voltage and is used for system reset as an example.

Each of these ICs consists of a voltage reference unit, a comparator, resistor net for detector threshold setting, an output driver, a hysteresis circuit, and an output delay circuit. The detector threshold is fixed with high accuracy internally and does not require any adjustment. Two output types, Nch open drain type and CMOS type are available.

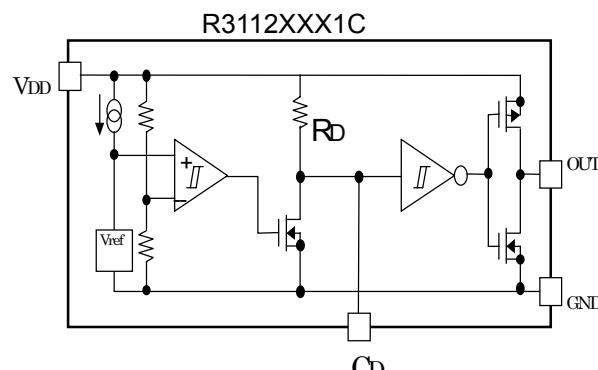
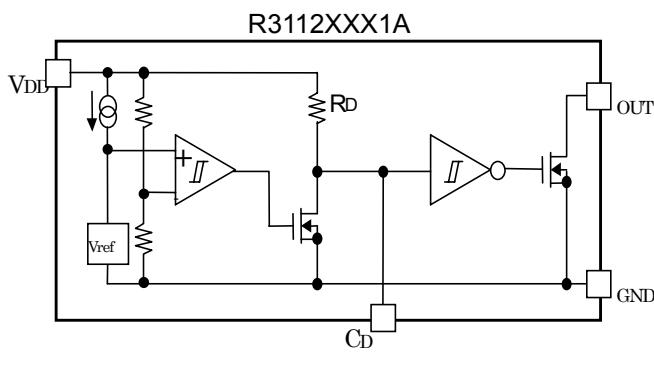
Two types of packages, SOT-23-5 and ultra small SC-82AB can be selected so that high density mounting on boards is possible.

■ FEATURES

- Built-in Output Delay Circuit TYP. 100ms with an external capacitor: 0.022μF
- Ultra-low Supply Current TYP. 1.0μA (VDD=3.5V)
- Wide Range of Operating Voltage 0.7V~6.0V(Topt=25°C)
- Detector Threshold Stepwise setting with a step of 0.1V in the range of 0.9V to 5.0V is possible.
- High Accuracy Detector Threshold ±2.0%
- Low Temperature-Drift Coefficient of Detector Threshold TYP. ±100ppm/°C
- Two Output Types Nch Open Drain and CMOS
- Two Types of Packages SOT-23-5 (Mini-mold), SC-82AB

■ APPLICATIONS

- CPU and Logic Circuit Reset
- Battery Checker
- Window Comparator
- Wave Shaping Circuit
- Battery Back-up Circuit
- Power Failure Detector

■ BLOCK DIAGRAMS

■ OPERATION

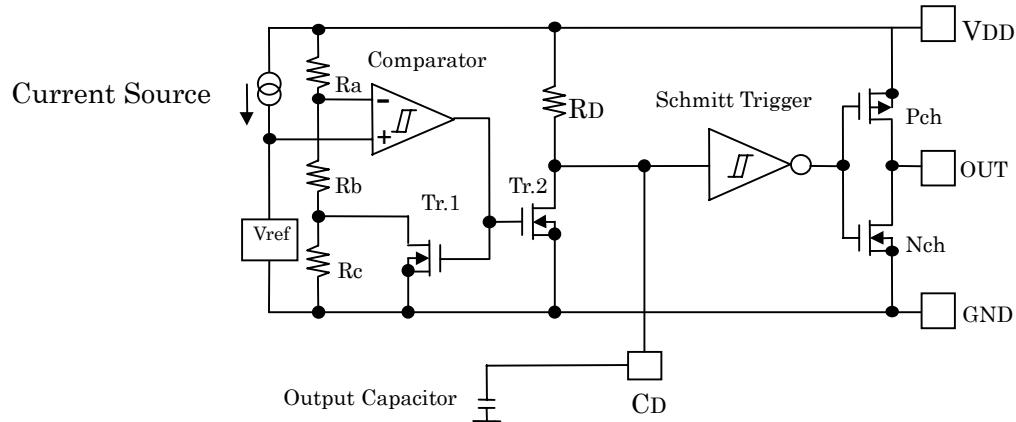
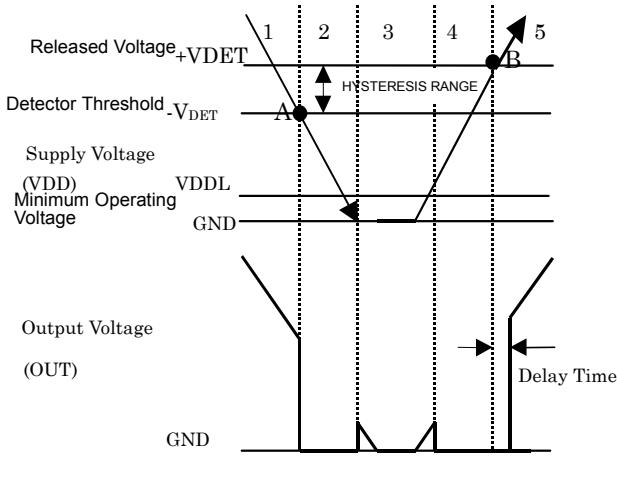


Fig. 1 Block Diagram with an external capacitor



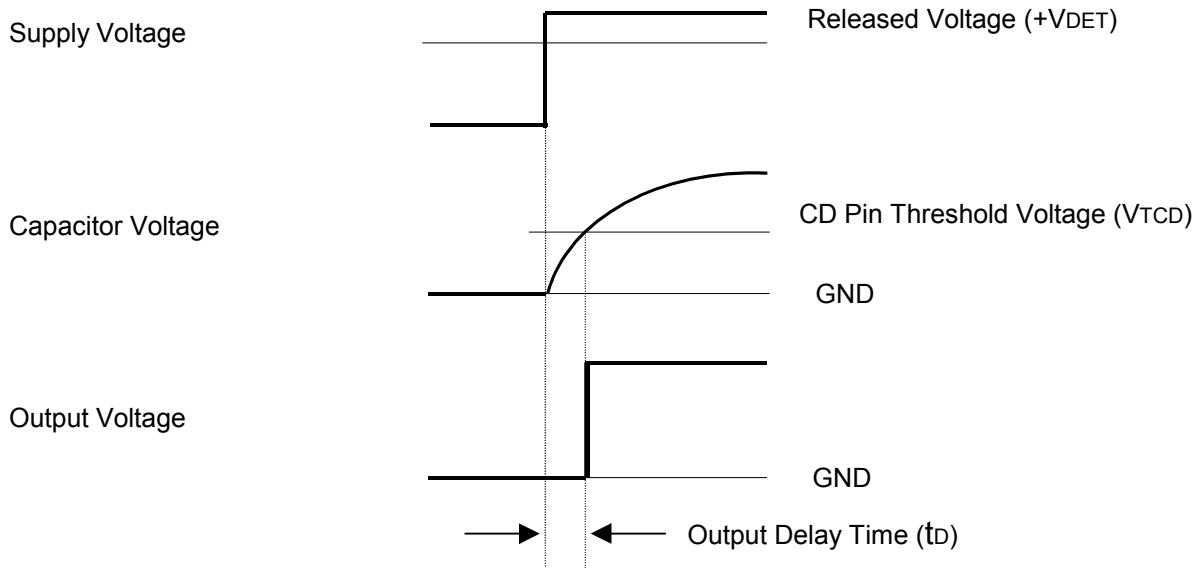
Operation Status	1	2	3	4	5
Comparator(-) Pin Input Voltage	I	II	II	II	I
Comparator Output	L	H	Indefinite	H	L
Tr.1, 2	OFF	ON	Indefinite	ON	OFF
Output Tr.	Nch	OFF	ON	Indefinite	ON
	Pch	ON	OFF	Indefinite	OFF

I $\frac{R_b+R_c}{R_a+R_b+R_c} \times V_{DD}$
 II $\frac{R_b}{R_a+R_b} \times V_{DD}$

Fig. 2 Operation Diagram

1. The output voltage is equal to supply voltage. (As for Nch open drain type, equal to pull-up voltage.)
 2. When the supply voltage is down to the detector threshold voltage level (Point A), $V_{ref} \geq V_{DD} \times (R_b + R_c) / (R_a + R_b + R_c)$ is true, then output of the comparator is reversed from "L" to "H", therefore the output voltage becomes GND level.
 3. When the supply voltage is lower than minimum operating voltage, the operation of output transistor is indefinite. In the case of Nch open drain type, the output voltage is equal to pull-up voltage.
 4. The output voltage becomes GND level.
 5. When the supply voltage is higher than released voltage (Point B), $V_{ref} \leq V_{DD} \times R_b / (R_a + R_b)$ is true, then the output of the comparator reaches the threshold level, and the output of Shmitt trigger is reversed from "H" to "L", then the output voltage is equal to the supply voltage. (As for Nch open drain type, equal to pull-up voltage.)
- *) The difference between the released voltage and the detector threshold voltage means the hysteresis range voltage.

● Operation of Output Delay



When the supply voltage which is higher than the released voltage is forced to VDD pin, charge to an external capacitor starts, then capacitor voltage increases. Until the capacitor voltage reaches to CD Pin threshold voltage, the output voltage maintains "L". When the capacitor voltage becomes higher than CD pin threshold voltage, the output voltage is reversed from "L" to "H". Where, the time interval between the rising edge of the supply voltage and the output voltage reverse point, means the output delay time.

● Output Delay Time

The output delay time (t_D) can be calculated with the next formula.

$$t_D = 0.69 \times R_D \times C_D(s)$$

R_D is internal resistor and set at $6.5M\Omega$ (TYP.) typically. $C_D(F)$ describes the capacitance value of an external capacitor. Therefore,

$$t_D = 0.69 \times 6.5 \times 10^6 \times C_D(s)$$

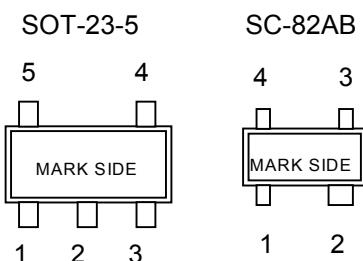
■ SELECTION GUIDE

The package type, the detector threshold, the output type, and the taping type of R3112 Series can be designated at the users' request by specifying the part number as follows;

R3112~~XXX~~1X-XX←Part Number
 ↑↑ ↑↑
 a b c d

Code	Contents
a	Designation of Package Type; Q:SC-82AB N:SOT-23-5
b	Setting Detector Threshold (-VDET); Stepwise setting with a step of 0.1V in the range of 0.9V to 5.0V is possible.
c	Designation of Output Type; A: Nch Open Drain C: CMOS
d	Designation of Packing or Taping Type ; Ex. SOT-23-5, SC-82AB: TR is prescribed as standard directions. (Refer to Taping Specifications)

■ PIN CONFIGURATION



■ PIN DESCRIPTION

SOT-23-5

Pin No.	Symbol	Description
1	OUT	Output Pin(Output "L" at detector threshold, Output "H" at released voltage)
2	VDD	Voltage Supply Pin
3	GND	Ground Pin
4	NC	No Connection
5	Cd	Pin for External Capacitor (for setting output delay)

SC-82AB

Pin No.	Symbol	Description
1	VDD	Voltage Supply Pin
2	GND	Ground Pin
3	Cd	Pin for External Capacitor (for setting output delay)
4	OUT	Output Pin(Output "L" at detector threshold, Output "H" at released voltage)

■ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
VDD	Supply Voltage	6.5	V
VOUT1	Output Voltage(CMOS)	Vss-0.3~VDD+0.3	V
VOUT2	Output Voltage(Nch)	Vss-0.3~6.5	V
IOUT	Output Current	20	mA
PD	Power Dissipation(SOT23-5)	250	mW
	Power Dissipation(SC82-AB)	150	
Topt	Operating Temperature Range	-40~85	°C
Tstg	Storage Temperature Range	-55~125	°C
Tsolder	Lead temperature (Soldering)	260°C, 10s	

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum ratings are threshold limit values that must not be exceeded ever for an instant under any conditions. Moreover, such values for any two items must not be reached simultaneously. Operation above these absolute maximum ratings may cause degradation or permanent damage to the device. These are stress ratings only and do not necessarily imply functional operation below these limits.

●R3112x091A/C

Topt=25°C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-VDET	Detector Threshold		0.882	0.900	0.918	V
VHYS	Detector Threshold Hysteresis		0.027	0.045	0.063	V
Iss	Supply Current	VDD=0.80V		0.6	2.0	μA
		1.90V		0.5	2.0	
VDDH	Maximum Operating Voltage				6.0	V
VDDL	Minimum Operating Voltage ^{*Note1}	Topt=25°C			0.70	V
		-40°C ≤ Topt ≤ 85°C			0.80	
IOUT	Output Current (Driver Output Pin)	Nch VDS=0.05V, VDD=0.70V VDS=0.50V, VDD=0.85V	10 0.05	120 0.90		μA
		Pch VDS=-2.1V, VDD=4.5V	1.0	3.5		mA
VTCD	CD pin Threshold Voltage	VDD=0.99V	0.297	0.495	0.693	V
ICD	CD pin Output Current	VDS=0.10V, VDD=0.70V	2	70		μA
		VDS=0.50V, VDD=0.85V	10	400		
RD	Output Delay Resistance		3.25	6.50	13.00	MΩ
Δ-VDET/ΔT	Detector Threshold Temperature Coefficient	-40°C ≤ Topt ≤ 85°C		±100		ppm/°C

●R3112x271A/C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-VDET	Detector Threshold		2.646	2.700	2.754	V
VHYS	Detector Threshold Hysteresis		0.081		0.189	V
Iss	Supply Current	VDD=2.60V		1.0	3.0	μA
		3.70V		0.5	2.5	
VDDH	Maximum Operating Voltage				6.0	V
VDDL	Minimum Operating Voltage ^{*Note1}	T _{opt} =25°C			0.7	V
		-40°C ≤ T _{opt} ≤ 85°C			0.8	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V	10	120		μA
		V _{DS} =0.50V, V _{DD} =1.50V	1.0	3.0		mA
		Pch V _{DS} =-2.1V, V _{DD} =4.5V	1.0	3.5		mA
V _{TCD}	CD pin Threshold Voltage	V _{DD} =2.97V	0.891	1.485	2.079	V
ICD	CD pin Output Current	V _{DS} =0.1V, V _{DD} =0.7V	2.0	70		μA
		V _{DS} =0.5V, V _{DD} =1.5V	200	500		
R _D	Output Delay Resistance		3.25	6.50	13.00	MΩ
Δ-VDET/ΔT	Detector Threshold Temperature Coefficient	-40°C ≤ T _{opt} ≤ 85°C		±100		ppm/°C

●R3112x501A/C

Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
-VDET	Detector Threshold		4.900	5.000	5.100	V
VHYS	Detector Threshold Hysteresis		0.150	0.250	0.350	V
Iss	Supply Current	V _{DD} =4.9V		1.5	3.0	μA
		6.0V		0.6	2.5	
VDDH	Maximum Operating Voltage				6.0	V
VDDL	Minimum Operating Voltage ^{*Note1}	T _{opt} =25°C			0.7	V
		-40°C ≤ T _{opt} ≤ 85°C			0.8	
I _{OUT}	Output Current (Driver Output Pin)	Nch V _{DS} =0.05V, V _{DD} =0.70V	10	120		μA
		V _{DS} =0.50V, V _{DD} =1.50V	1.0	3.0		mA
		Pch V _{DS} =-2.1V, V _{DD} =6.0V	1.5	4.5		mA
V _{TCD}	CD pin Threshold Voltage	V _{DD} =5.50V	1.650	2.750	3.850	V
ICD	CD pin Output Current	V _{DS} =0.1V, V _{DD} =0.7V	2.0	70		μA
		V _{DS} =0.5V, V _{DD} =1.5V	200	500		
R _D	Output Delay Resistance		3.25	6.50	13.00	MΩ
Δ-VDET/ΔT	Detector Threshold Temperature Coefficient	-40°C ≤ T _{opt} ≤ 85°C		±100		ppm/°C

*Note1: The minimum operating voltage means the value of input voltage when output voltage maintains 0.1V or less.

(In the case of Nch open drain type, the output pin is pulled up with a resistance of 470kΩ to 5.0V.)

■ ELECTRICAL CHARACTERISTICS BY DETECTOR THRESHOLD

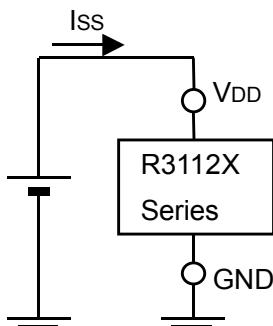
Product Code	Detector Threshold			Hysteresis Range			Supply Current1			Supply Current2			Output Current1			Output Current2		
	-VDET [V]			VHYS [V]			Iss1 [uA]			Iss2 [uA]			IOUT1 [mA]			IOUT2 [mA]		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	Condition	TYP.	MAX.	Condition	TYP.	MAX.	Condition	MIN.	TYP.	Conditions	MIN.	TYP.
R3112x091A/C	0.882	0.900	0.918	0.027	0.045	0.063	VDD= -VDET-0.1V	0.6	2.0	0.5	2.0	Vds=0.05V Vdd=0.85V	0.01	0.12	Nch	0.05	0.9	
R3112x101A/C	0.980	1.000	1.020	0.030	0.050	0.070												
R3112x111A/C	1.078	1.100	1.122	0.033	0.055	0.077												
R3112x121A/C	1.176	1.200	1.224	0.036	0.060	0.084												
R3112x131A/C	1.274	1.300	1.326	0.039	0.065	0.091												
R3112x141A/C	1.372	1.400	1.428	0.042	0.070	0.098												
R3112x151A/C	1.470	1.500	1.530	0.045	0.075	0.105												
R3112x161A/C	1.568	1.600	1.632	0.048	0.080	0.112												
R3112x171A/C	1.666	1.700	1.734	0.051	0.085	0.119												
R3112x181A/C	1.764	1.800	1.836	0.054	0.090	0.126												
R3112x191A/C	1.862	1.900	1.938	0.057	0.095	0.133	VDD= -VDET+1.0V	0.7	2.5	0.5	2.5	Vds=0.05V Vdd=0.7V	0.01	0.12	Nch	0.2	1.8	
R3112x201A/C	1.960	2.000	2.040	0.060	0.100	0.140												
R3112x211A/C	2.058	2.100	2.142	0.063	0.105	0.147												
R3112x221A/C	2.156	2.200	2.244	0.066	0.110	0.154												
R3112x231A/C	2.254	2.300	2.346	0.069	0.115	0.161												
R3112x241A/C	2.352	2.400	2.448	0.072	0.120	0.168												
R3112x251A/C	2.450	2.500	2.550	0.075	0.125	0.175												
R3112x261A/C	2.548	2.600	2.652	0.078	0.130	0.182												
R3112x271A/C	2.646	2.700	2.754	0.081	0.135	0.189												
R3112x281A/C	2.744	2.800	2.856	0.084	0.140	0.196												
R3112x291A/C	2.842	2.900	2.958	0.087	0.145	0.203	VDD= -VDET-0.1V	1.0	3.0	0.5	2.5	Vds=0.05V Vdd=0.7V	0.01	0.12	Nch	0.5	1.0	
R3112x301A/C	2.940	3.000	3.060	0.090	0.150	0.210												
R3112x311A/C	3.038	3.100	3.162	0.093	0.155	0.217												
R3112x321A/C	3.136	3.200	3.264	0.096	0.160	0.224												
R3112x331A/C	3.234	3.300	3.366	0.099	0.165	0.231												
R3112x341A/C	3.332	3.400	3.468	0.102	0.170	0.238												
R3112x351A/C	3.430	3.500	3.570	0.105	0.175	0.245												
R3112x361A/C	3.528	3.600	3.672	0.108	0.180	0.252												
R3112x371A/C	3.626	3.700	3.774	0.111	0.185	0.259												
R3112x381A/C	3.724	3.800	3.876	0.114	0.190	0.266												
R3112x391A/C	3.822	3.900	3.978	0.117	0.195	0.273	VDD= -VDET+1.0V	1.2	3.0	0.6	2.5	Vds=0.5V Vdd=1.5V	0.01	0.12	Nch	0.5	1.0	
R3112x401A/C	3.920	4.000	4.080	0.120	0.200	0.280												
R3112x411A/C	4.018	4.100	4.182	0.123	0.205	0.287												
R3112x421A/C	4.116	4.200	4.284	0.126	0.210	0.294												
R3112x431A/C	4.214	4.300	4.386	0.129	0.215	0.301												
R3112x441A/C	4.312	4.400	4.488	0.132	0.220	0.308												
R3112x451A/C	4.410	4.500	4.590	0.135	0.225	0.315												
R3112x461A/C	4.508	4.600	4.692	0.138	0.230	0.322												
R3112x471A/C	4.606	4.700	4.794	0.141	0.235	0.329												
R3112x481A/C	4.704	4.800	4.896	0.144	0.240	0.336												
R3112x491A/C	4.802	4.900	4.998	0.147	0.245	0.343	VDD= -VDET-0.1V	1.5	3.0	0.6	2.5	Vds=0.5V Vdd=1.5V	0.01	0.12	Nch	0.5	1.0	
R3112x501A/C	4.900	5.000	5.100	0.150	0.250	0.350												



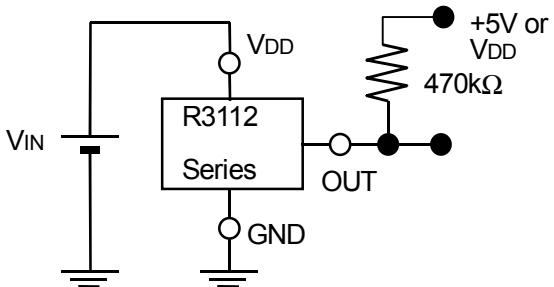
TEST CIRCUITS

*Pull-up circuit is not necessary for CMOS Output type, or R3112XXXXC.

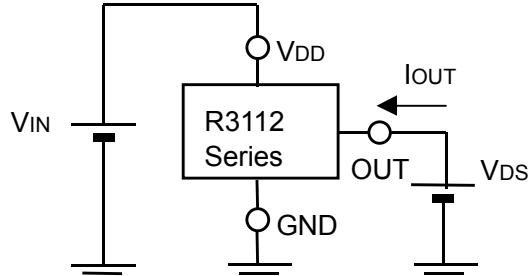
Supply Current Test Circuit



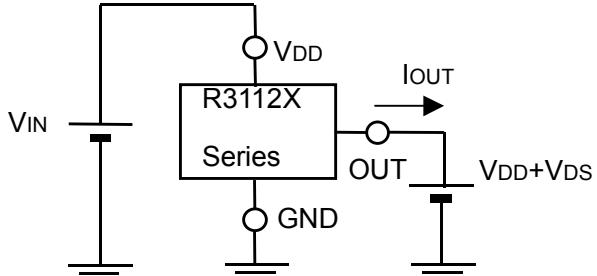
Detector Threshold Test Circuit



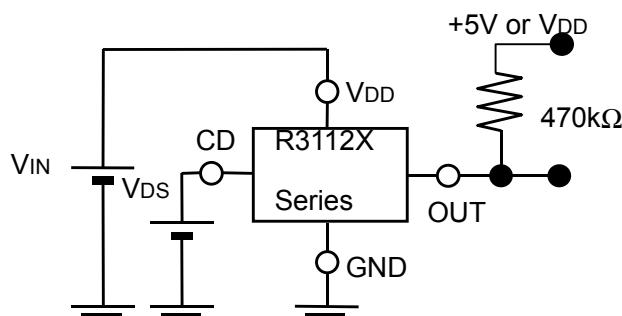
Nch Driver Output Current Test Circuit



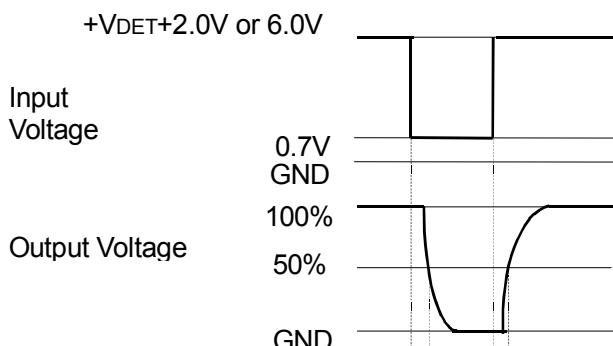
Pch Driver Output Current Test Circuit *Apply only to CMOS



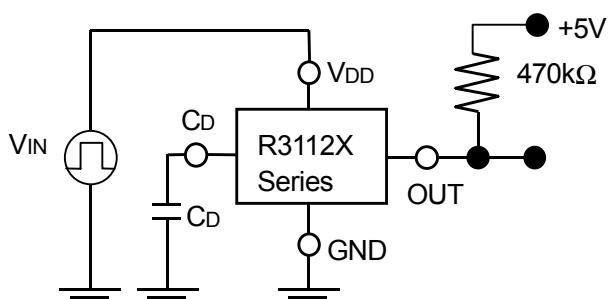
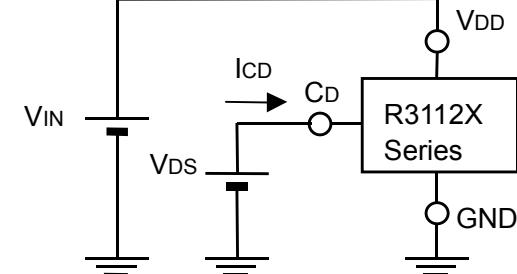
CD Pin Threshold Test Circuit



Output Delay Time Test Circuit



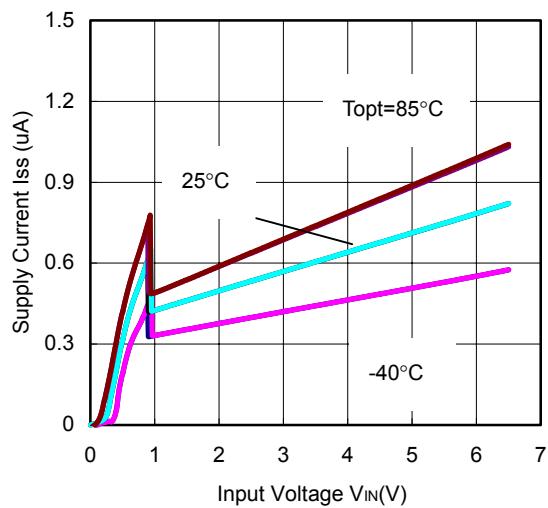
CD Pin Output Current Test Circuit



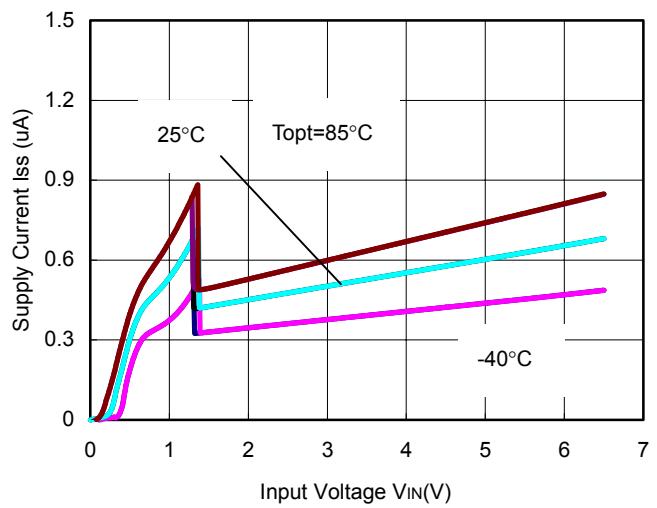
■ TYPICAL CHARACTERISTICS

1) Supply Current vs. Input Voltage

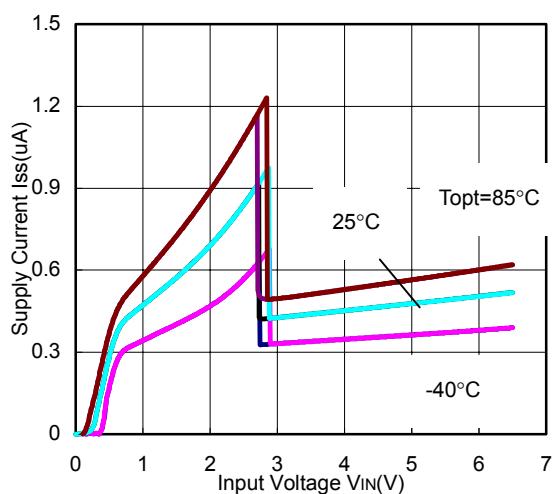
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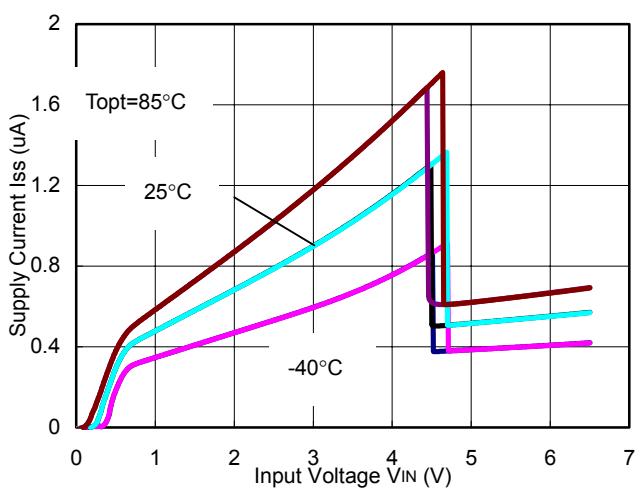
R3112X131X



R3112X271X

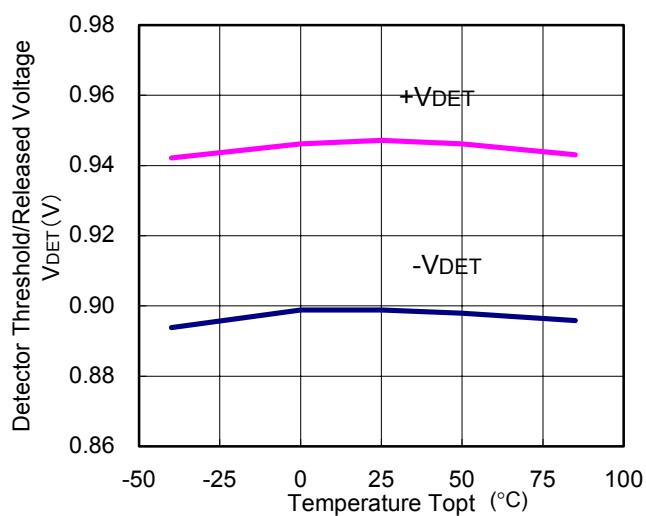


R3112X451X

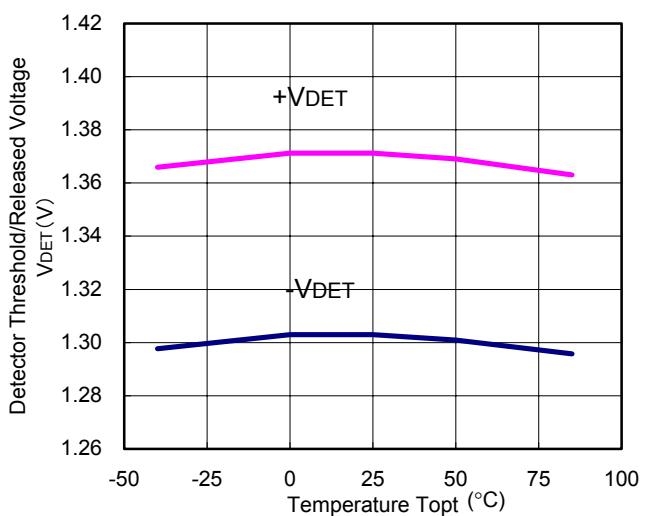


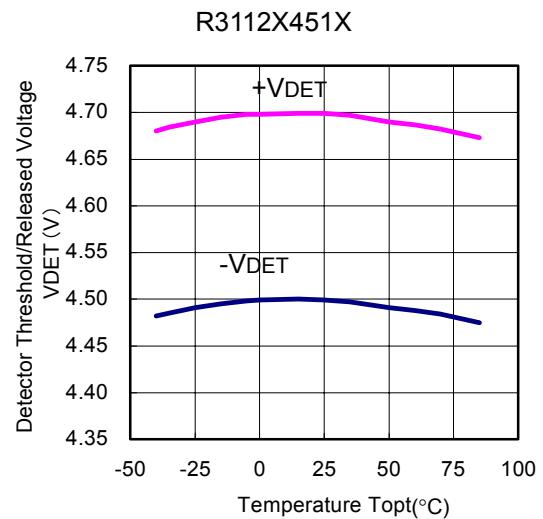
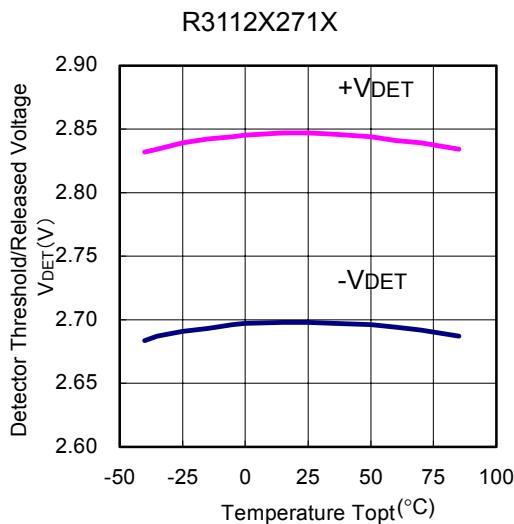
2) Detector Threshold vs. Temperature

R3112X091X

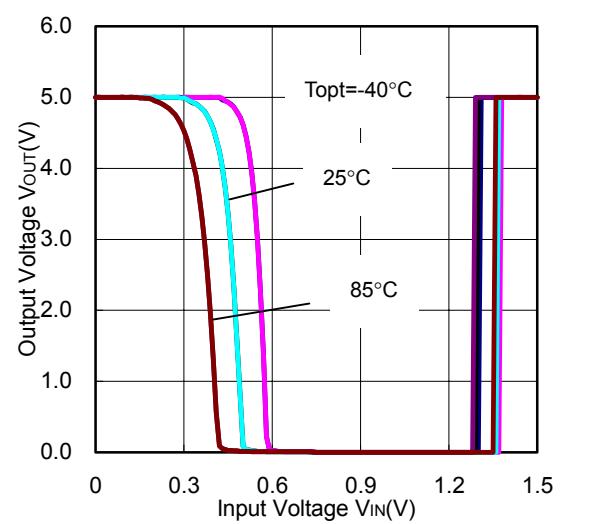
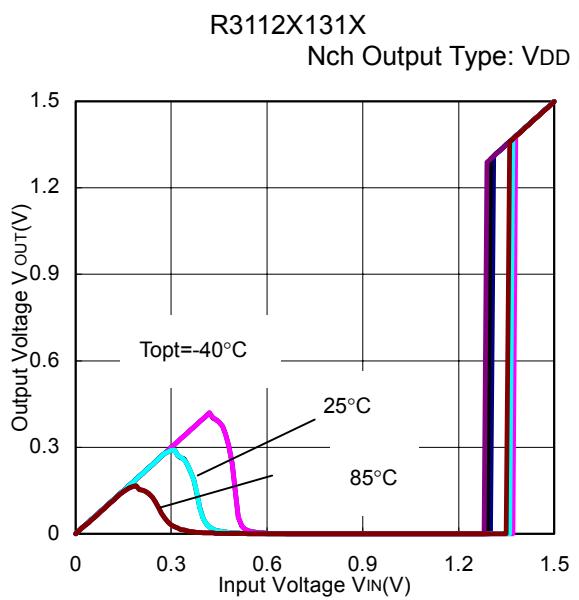
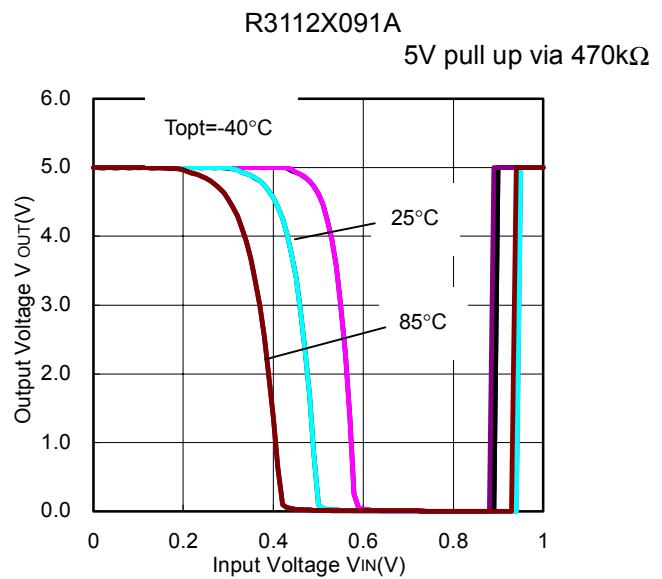
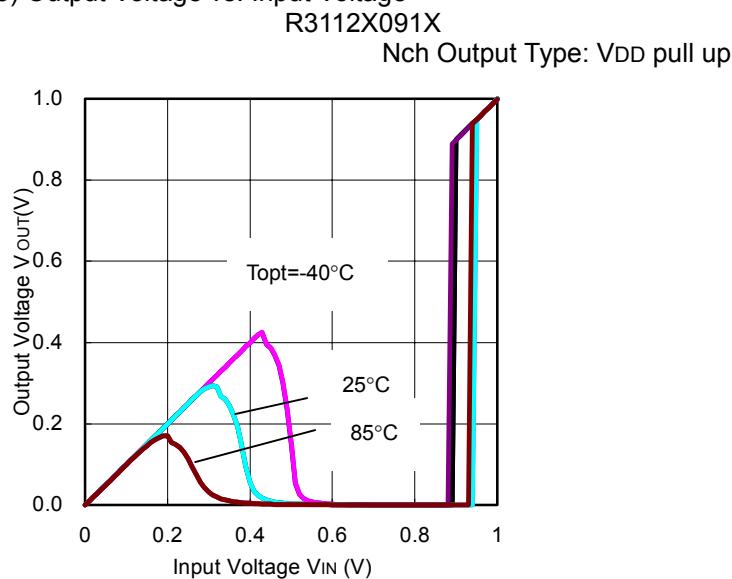


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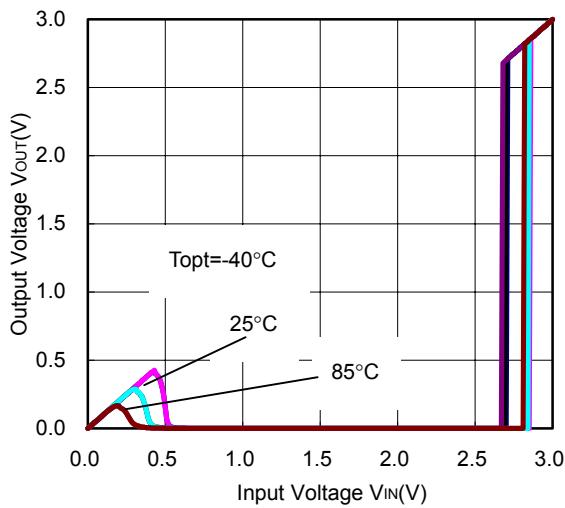




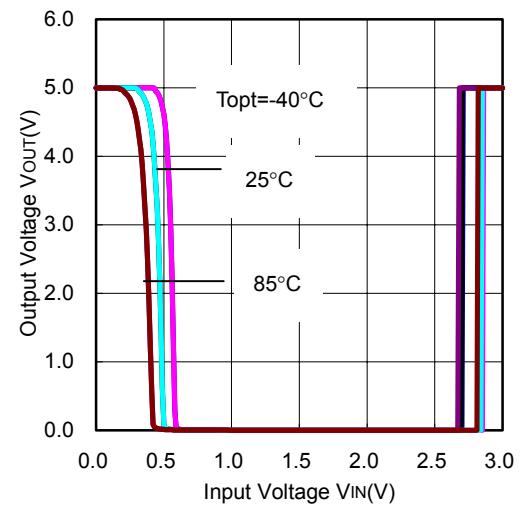
3) Output Voltage vs. Input Voltage



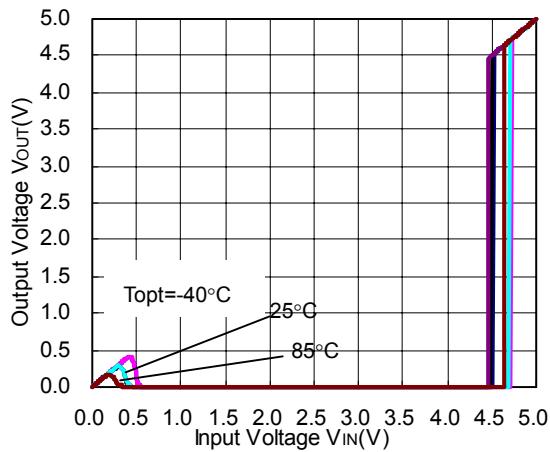
R3112X271X
Nch Output Type: VDD pull up



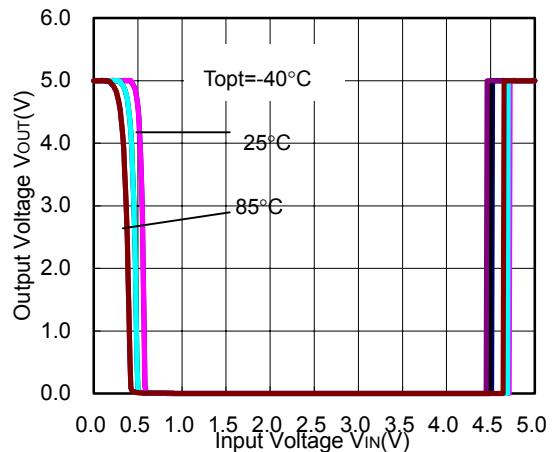
R3112X271A
5V pull up via $470k\Omega$



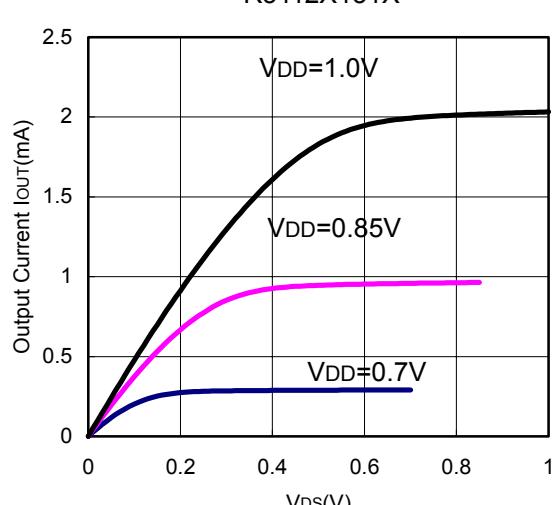
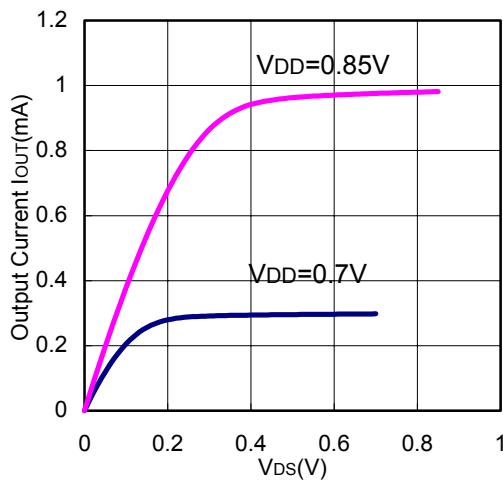
R3112X451X
Nch Output Type: VDD pull up

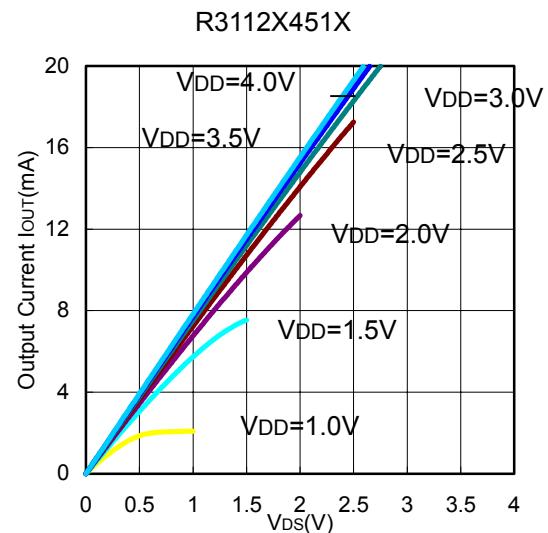
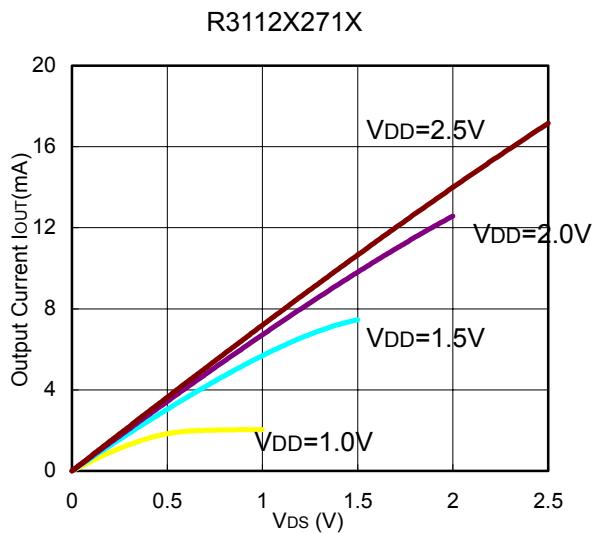


R3112X451A
5V pull up via $470k\Omega$

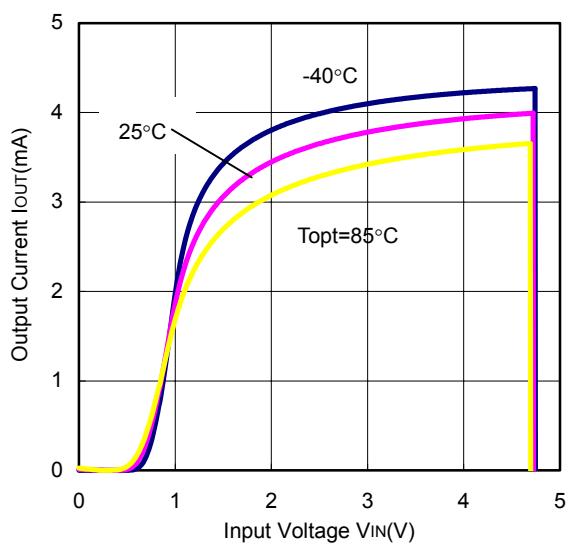
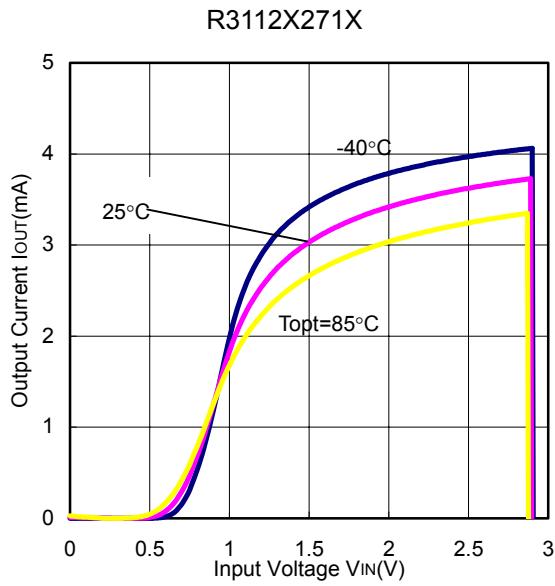
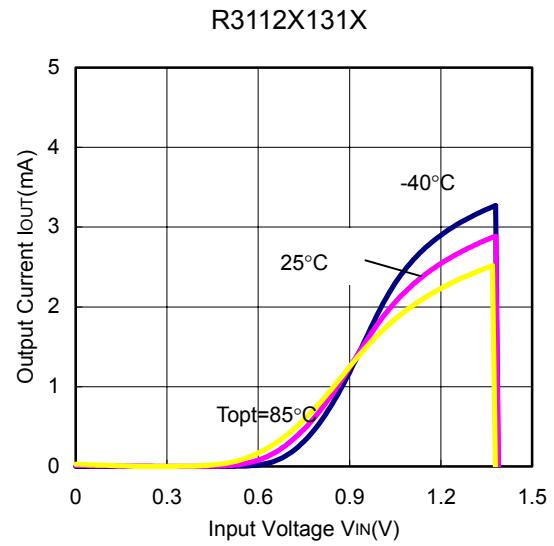
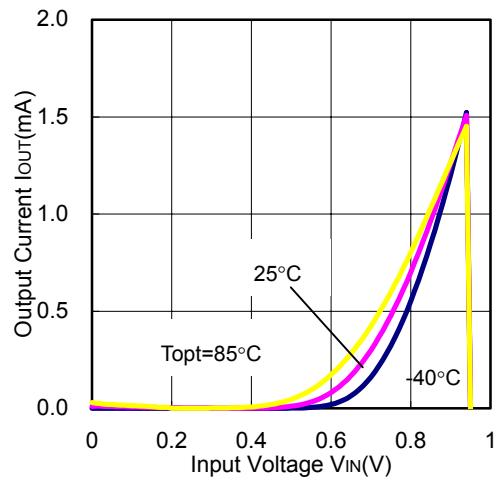


4) Nch Driver Output Current vs. V_{DS}
R3112X091X

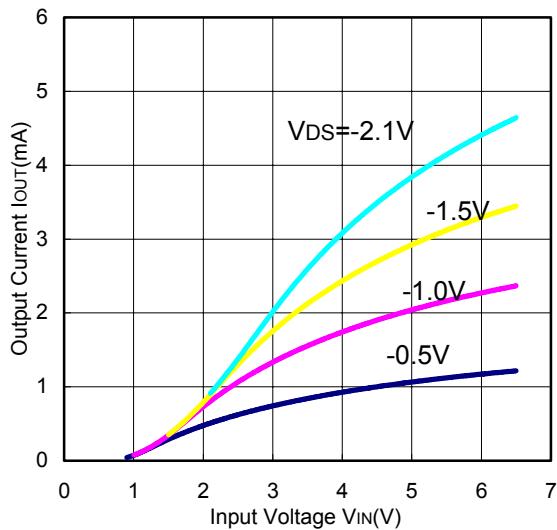




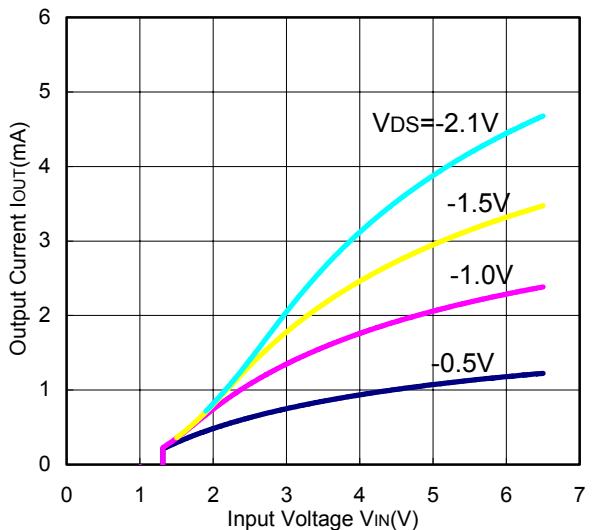
5) Nch Driver Output Current vs. Input Voltage
R3112X091X



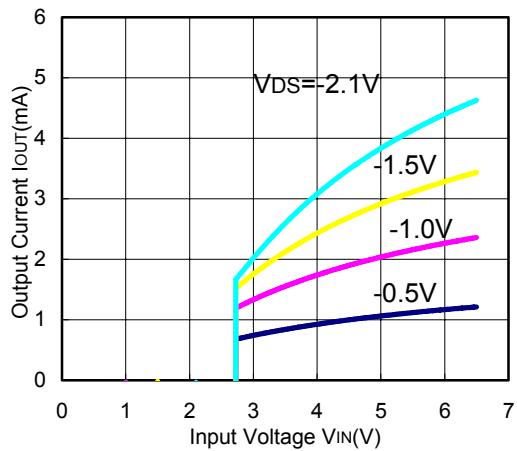
6) Pch Driver Output Current vs. Input Voltage
R3112X091C



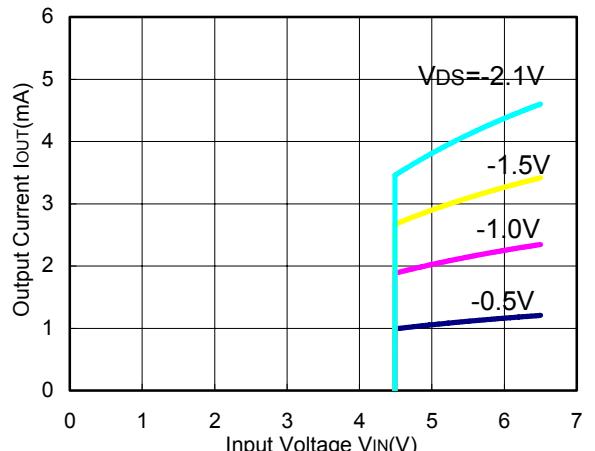
R3112X131C



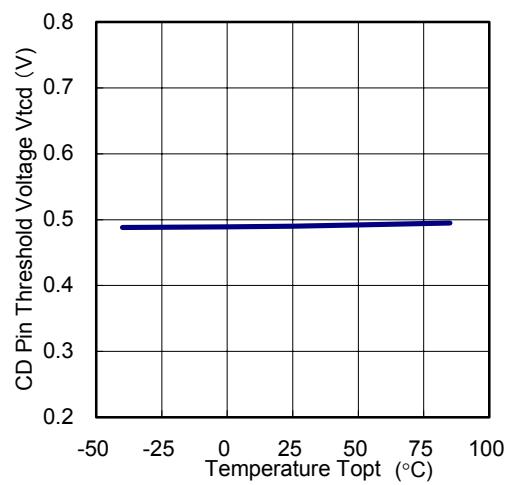
R3112X271C



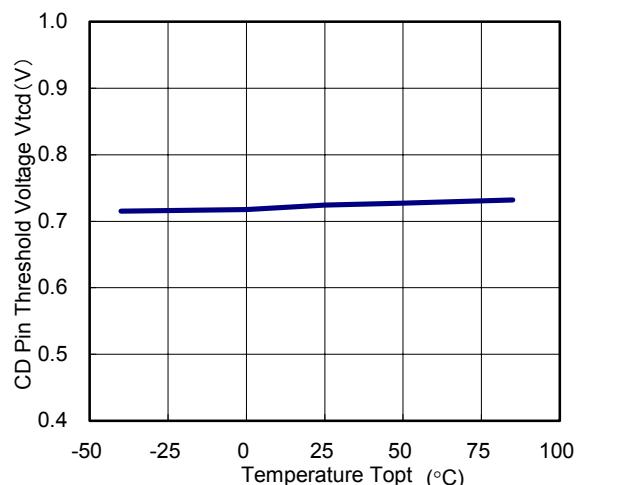
R3112X451C



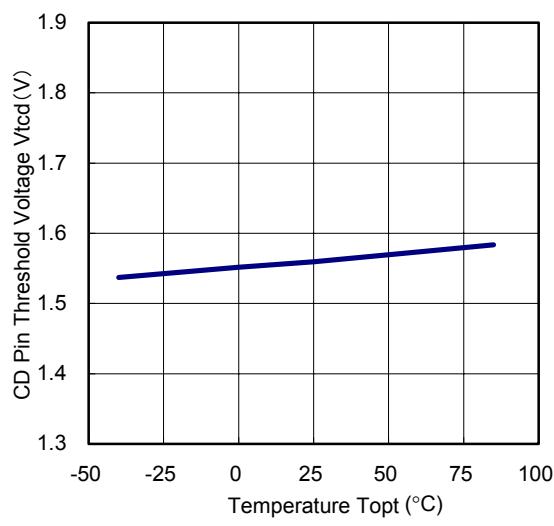
7) CD Pin Threshold Voltage vs. Temperature
R3112X091X $V_{DD} = 0.99V$



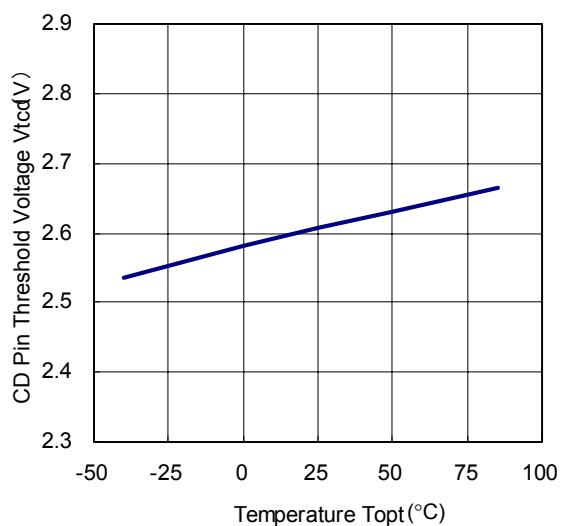
R3112X131X



R3112X271X VDD=2.97V

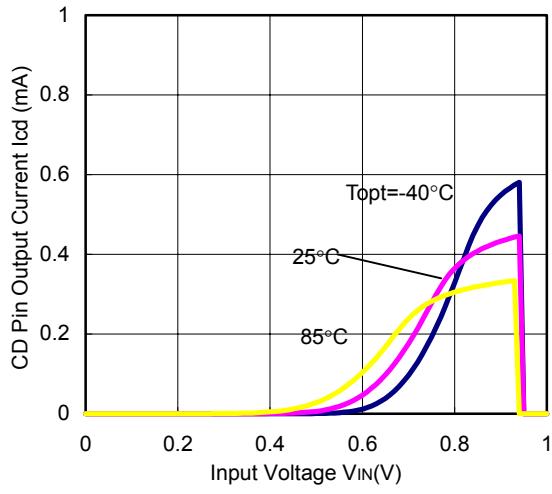


R3112X451X VDD=4.95V

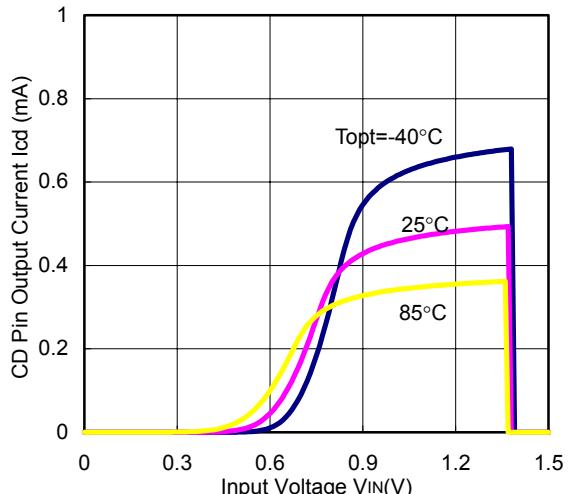


8) CD Pin Output Current vs. Input Voltage

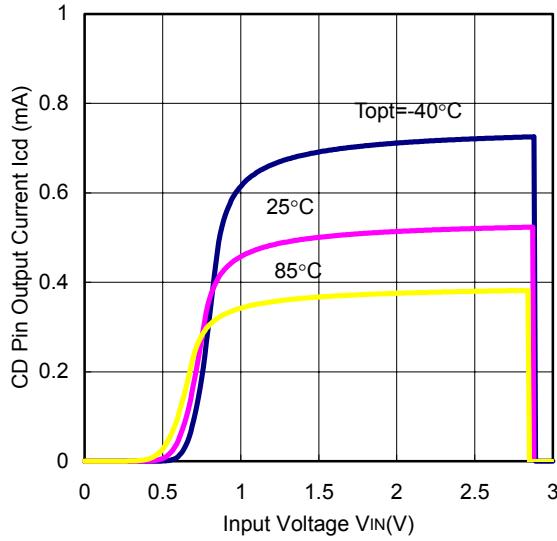
R3112X091X VDS=0.5V



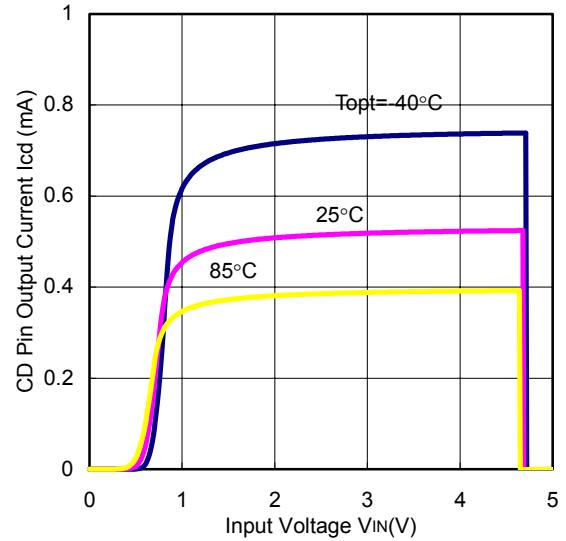
R3112X131X VDS=0.5V



R3112X271X VDS=0.5V

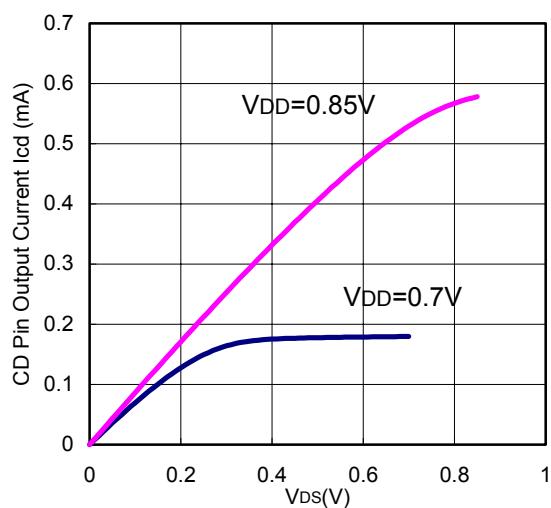


R3112X451X VDS=0.5V

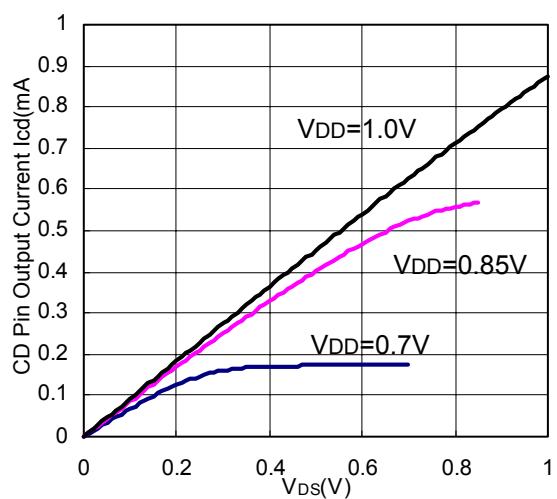


9) CD Pin Output Current vs. V_{DS} (T_{opt}=25°C)

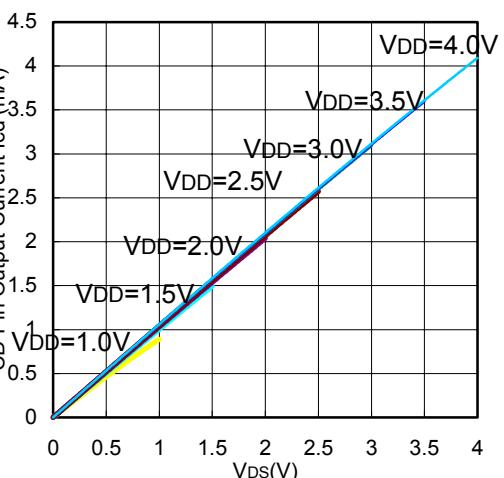
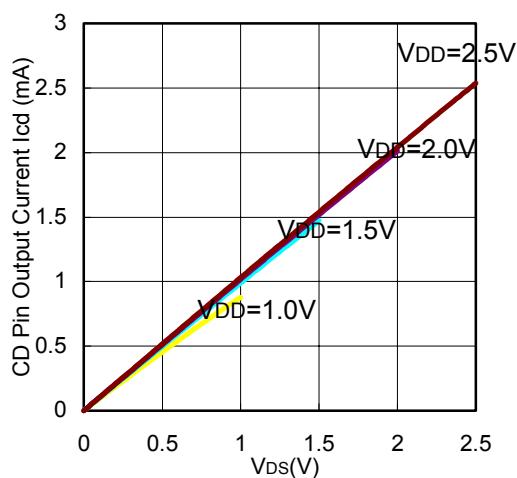
R3112X091X



R3112X131X

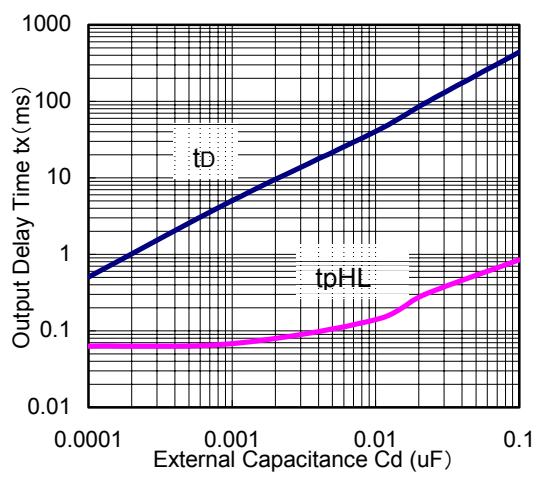


R3112X271X



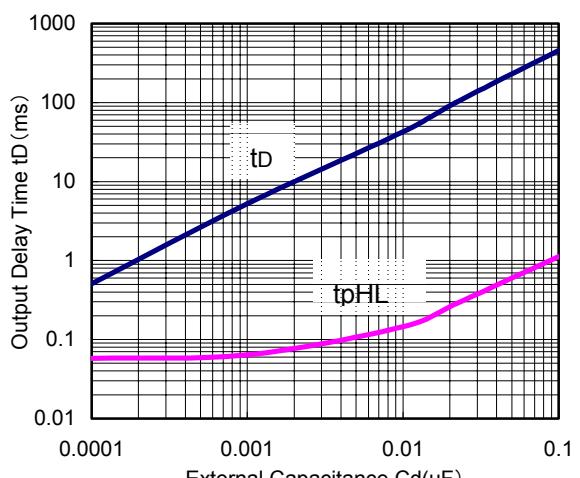
10) Output Delay Time vs. External Capacitance

R3112X091X

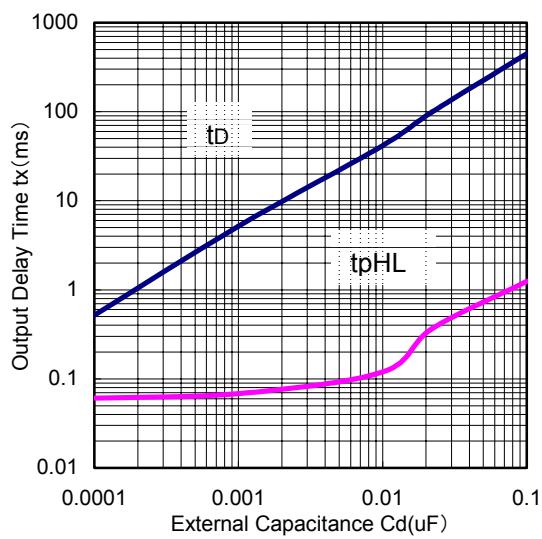


(T_{opt}=25°C)

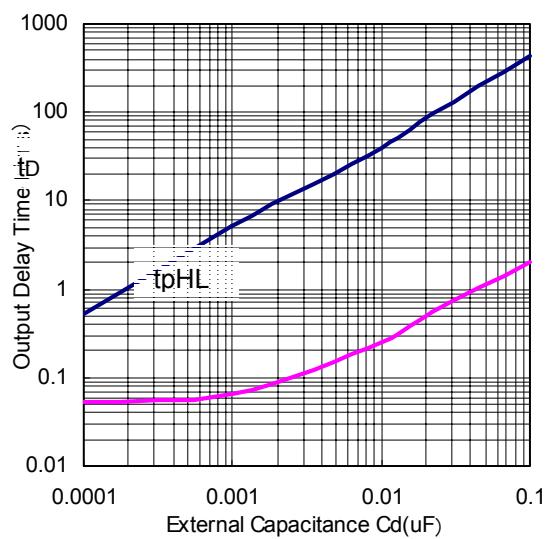
R3112X131X



R3112X271X

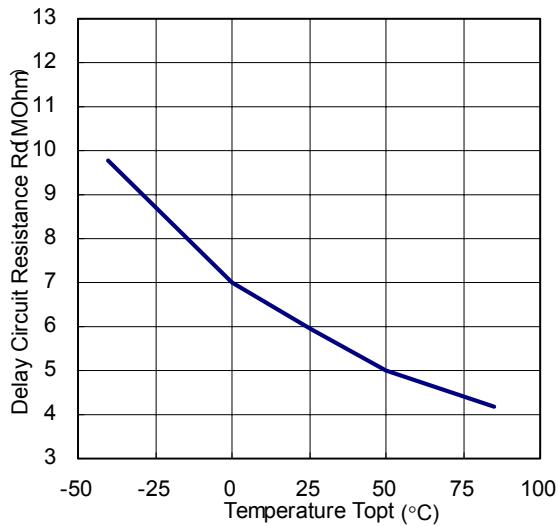


R3112X451X

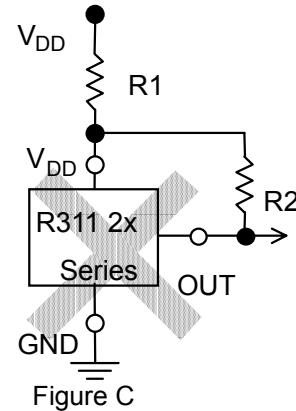
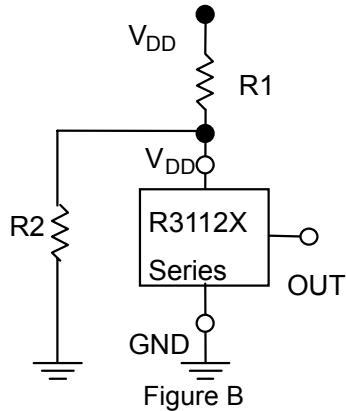
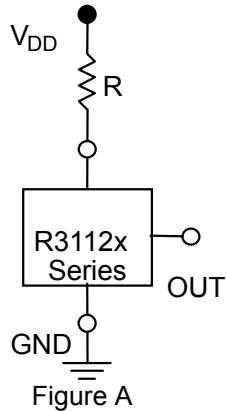


11) Delay Circuit Resistance vs. Temperature

R3112XXX1X



■ TECHNICAL NOTES



When R3112XXX1A (Nch open drain output type) is used in Figure A or Figure B, if the impedance between the voltage supply pin, VDD and VDD of this IC is large, detector threshold level would shift by voltage dropdown caused by the consumption current of the IC itself. The released voltage may also shift and delay time for start-up might be generated by this usage.

When R3112XXX1C (CMOS output Type) is used in Figure A or Figure B, the output level could be unstable by throughout current which is generated at detector threshold level or at released voltage level, therefore, do not use R3112XXX1C with the connection in Figure A or Figure B.

The connection in Figure C may cause the oscillation in both R3112XXX1C (CMOS Output) and R3112XXX1A (Nch Open Drain Output), therefore do not use R3112XXX1X series with the connection in Figure C.